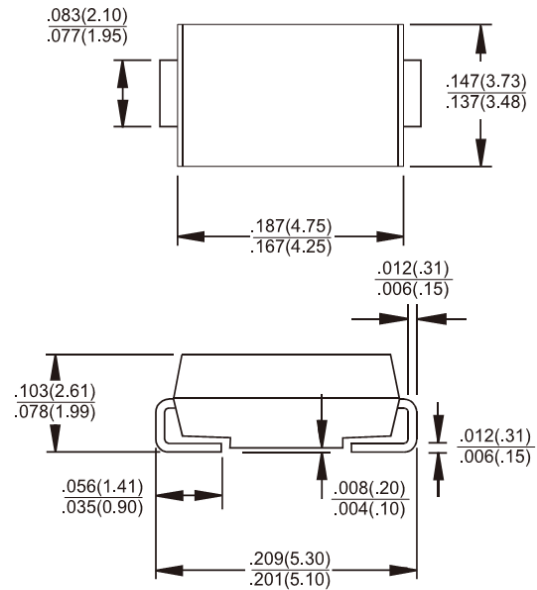


**SMB/DO-214AA**

**Features**

- ✧ Glass passivated junction chip
- ✧ For surface mounted application
- ✧ Low profile package
- ✧ Built-in strain relief
- ✧ Ideal for automated placement
- ✧ Easy pick and place
- ✧ Super fast recovery time for high efficiency
- ✧ Glass passivated chip junction
- ✧ High temperature soldering:  
260°C/10 seconds at terminals
- ✧ Plastic material used carries Underwriters  
Laboratory Classification 94V-0
- ✧ Qualified as per AEC-Q101
- ✧ Green compound with suffix "G" on packing  
code & prefix "G" on datecode


**Mechanical Data**

- ✧ Cases: Molded plastic
- ✧ Terminals: Pure tin plated, lead free
- ✧ Polarity: Indicated by cathode band
- ✧ Packing: 12mm tape per EIA STD RS-481
- ✧ Weight: 0.093 grams

**Dimensions in inches and (millimeters)**
**Marking Diagram**


- ES2X = Specific Device Code
- G = Green Compound
- Y = Year
- M = Work Month

**Maximum Ratings and Electrical Characteristics**

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	ES 2A	ES 2B	ES 2C	ES 2D	ES 2F	ES 2G	ES 2H	ES 2J	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	$V_{RMS}$	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	2								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	50								A
Maximum Instantaneous Forward Voltage (Note 1) @ 2 A	$V_F$	0.95			1.3		1.7			V
Maximum DC Reverse Current @ $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A=125^\circ\text{C}$	$I_R$					10				uA
						350				uA
Maximum Reverse Recovery Time (Note 2)	$T_{rr}$					35				nS
Typical Junction Capacitance (Note 3)	$C_j$	25			20					pF
Maximum Thermal Resistance	$R_{\theta JA}$ $R_{\theta JL}$					75				$^\circ\text{C/W}$
						20				
Operating Temperature Range	$T_J$					- 55 to + 150				$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$					- 55 to + 150				$^\circ\text{C}$

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle

 Note 2: Reverse Recovery Test Conditions:  $I_F=0.5\text{A}$ ,  $I_R=1.0\text{A}$ ,  $I_{RR}=0.25\text{A}$ 

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

## RATINGS AND CHARACTERISTIC CURVES (ES2A THRU ES2J)

FIG. 1- MAXIMUM FORWARD CURRENT DERATING CURVE

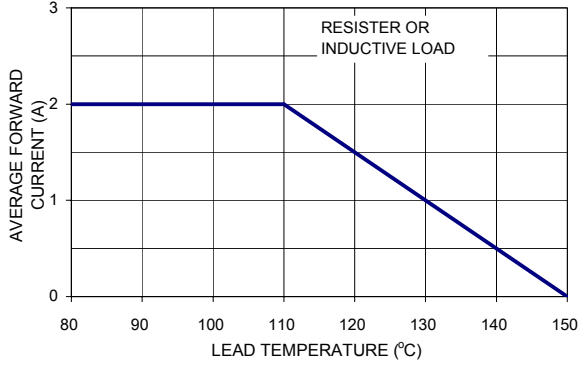


FIG. 2- TYPICAL REVERSE CHARACTERISTICS

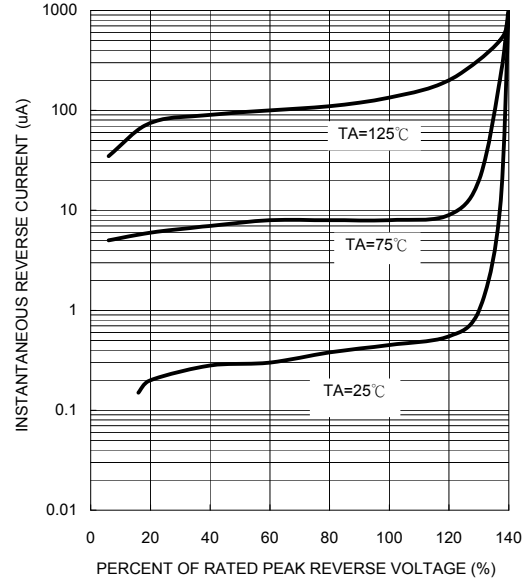


FIG. 3- MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

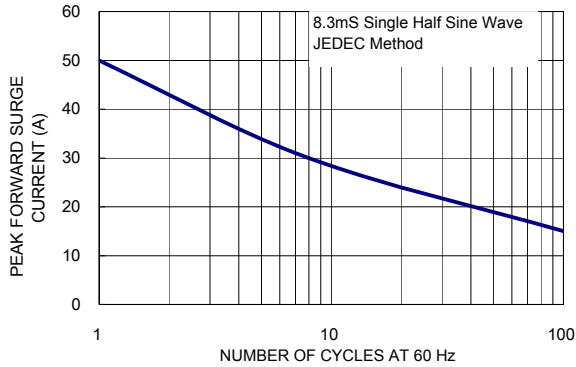


FIG. 5- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

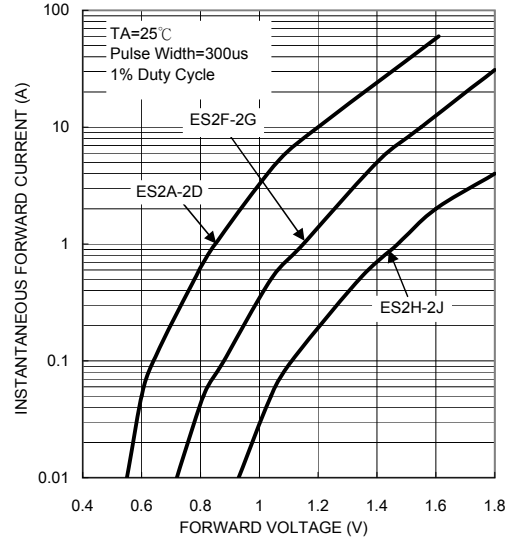


FIG. 4- TYPICAL JUNCTION CAPACITANCE

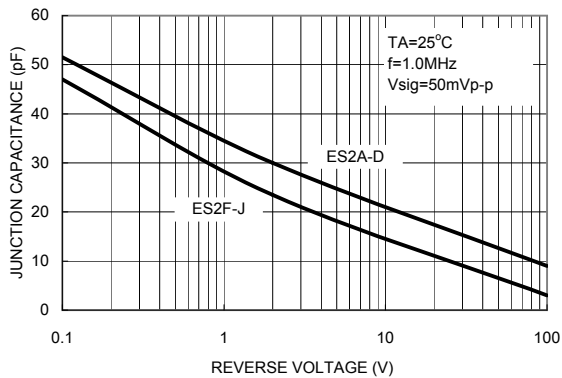


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

